

Gort Road Business Park, Ennis, Co. Clare, Ireland Tel: +353 (0) 65 6840044 Fax: +353 (0) 65 6822298

6 Lake Street, Lawrence, MA 01841 1-800-446-1158 / (978) 620-2600 / Fax: (978) 689-0803 Website: http://www.microsemi.com

NPN SILICON TRANSISTOR

Qualified per MIL-PRF-19500/317

DEVICES

2N2369A 2N2369AUB 2N4449 2N2369AU 2N2369AUBC *

2N2369AUA

JAN
JANTX
JANTXV
JANS

ABSOLUTE MAXIMUM RATINGS ($T_C = +25$ °C unless otherwise noted)

Parameters / Te	Symbol	Value	Unit	
Collector-Emitter Voltage		V_{CEO}	15	Vdc
Emitter-Base Voltage		V_{EBO}	4.5	Vdc
Collector-Base Voltage		V _{CBO}	40	Vdc
Collector-Emitter Voltage		I _{CES}	40	Vdc
Total Power Dissipation @ $T_A = +25$ °C	2N2369A; 2N4449 UA, UB, UBC U	P_{T}	0.36 ⁽¹⁾ 0.36 ^(1, 3) 0.50 ⁽²⁾	W
Operating & Storage Junction	Temperature Range	Top, Tstg	-65 to +200	°C

THERMAL CHARACTERISTICS

Parameters / Test Conditions	Symbol	Value	Unit
Thermal Resistance, Ambient-to-Case			
2N2369A; 2N4449 UA, UB, UBC	$R_{\theta JA}$	400 486 ⁽³⁾	°C/W
U		350	

Note:

- 1. Derate linearly 2.06 mW $^{\circ}$ /C above T_A = +25 $^{\circ}$ C.
- 2. Derate linearly 3.44 mW $^{\circ}$ /C above T_A = +54.5 $^{\circ}$ C.
- 3. Mounted on FR-4 PCB (1Oz. Cu) with contacts 20 mils larger than package pads.

ELECTRICAL CHARACTERISTICS ($T_A = +25$ °C, unless otherwise noted)

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
OFF CHARACTERTICS				
Collector-Emitter Breakdown Voltage I _C = 10mAdc	V _{(BR)CEO}	15		Vdc
Collector-Base Cutoff Current $V_{CE} = 20Vdc$	I_{CES}		0.4	μAdc



TO-18 (TO-206AA) 2N2369A



TO-46 (TO-206AB) 2N4449



SURFACE MOUNT UA



SURFACE MOUNT
UB & UBC
(UBC = Ceramic Lid Version)



SURFACE MOUNT U (Dual Transistor)

T4-LDS-0057 Rev. 3 (110213) Page 1 of 8

^{*} Available to JANS quality level only.



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ELECTRICAL CHARACTERISTICS ($T_A = +25^{\circ}C$, unless otherwise noted)

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS				
	I_{EBO}		10 0.25	μAdc
Collector- Base Cutoff Current $V_{CB} = 40 V dc$ $V_{CB} = 32 V dc$	I_{CBO}		10 0.2	μAdc
ON CHARACTERISTICS (1)				
Forward-Current Transfer Ratio $I_C = 10 \text{mAdc}, \ V_{CE} = 0.35 \text{Vdc}$ $I_C = 30 \text{mAdc}, \ V_{CE} = 0.4 \text{Vdc}$ $I_C = 10 \text{mAdc}, \ V_{CE} = 1.0 \text{Vdc}$ $I_C = 100 \text{mAdc}, \ V_{CE} = 1.0 \text{Vdc}$	${ m h_{FE}}$	40 30 40 20	120 120 120 120	
	$V_{\text{CE(sat)}}$		0.20 0.25 0.45	Vdc
$\begin{aligned} & Base\text{-Emitter Saturation Voltage} \\ & I_C = 10 \text{mAdc}, I_B = 1.0 \text{mAdc} \\ & I_C = 30 \text{mAdc}, I_B = 3.0 \text{mAdc} \\ & I_C = 100 \text{mAdc}, I_B = 10 \text{mAdc} \end{aligned}$	$ m V_{BE(sat)}$	0.70 0.80	0.85 0.90 1.20	Vdc

DYNAMIC CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Forward Current Transfer Ratio $I_C = 10 \text{mAdc}$, $V_{CE} = 10 \text{Vdc}$, $f = 100 \text{MHz}$	$ h_{\mathrm{fe}} $	5.0	10	
Output Capacitance $V_{CB} = 5.0 Vdc, I_E = 0, 100 kHz \le f \le 1.0 MHz$	$C_{ m obo}$		4.0	pF
Input Capacitance $V_{EB} = 0.5 Vdc, I_C = 0, 100 kHz \le f \le 1.0 MHz$	C_{ibo}		5.0	pF

SWITCHING CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Turn-On Time $I_C = 10$ mAdc; $I_{B1} = 3.0$ mAdc, $I_{B2} = -1.5$ mAdc	t_{on}		12	ηs
Turn-Off Time $I_C = 10$ mAdc; $I_{B1} = 3.0$ mAdc, $I_{B2} = -1.5$ mAdc	$t_{ m off}$		18	ηs
Charge Storage Time $I_C = 10 \text{mAdc}$; $I_{B1} = 10 \text{mAdc}$, $I_{B2} = 10 \text{mAdc}$	t_{S}		13	ηs

(1) Pulse Test: Pulse Width = $300\mu s$, Duty Cycle $\leq 2.0\%$.

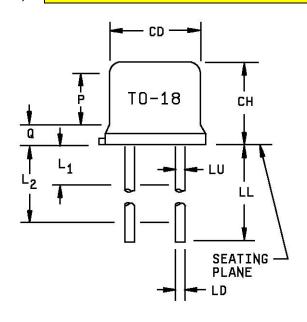
T4-LDS-0057 Rev. 3 (110213) Page 2 of 8

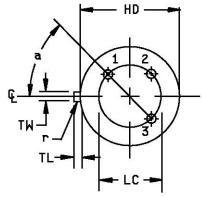


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PACKAGE DIMENSIONS





Dimensions						
Ltr	Inc	hes	Millimeters		Notes	
	Min	Max	Min	Max		
CD	.178	.195	4.52	4.95		
СН	.170	.210	4.32	5.33		
HD	.209	.230	5.31	5.84		
LC	.100) TP	2.54	TP	6	
LD	.016	.021	0.41	0.53	7,8	
LL	.500	.750	12.70	19.05	7,8,13	
LU	.016	.019	0.41	0.48	7,8	
L_1		.050		1.27	7,8	
L_2	.250		6.35		7,8	
P	.100		2.54		5	
Q		.030		0.76	5	
TL	.028	.048	0.71	1.22	3,4	
TW	.036	.046	0.91	1.17	3	
r		.010		0.25	10	
α	45°	TP	45°	TP	6	

NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Beyond r (radius) maximum, TH shall be held for a minimum length of .011 (0.28 mm).
- 4. Dimension TL measured from maximum HD.
- 5. Body contour optional within zone defined by HD, CD, and Q.
- 6. Leads at gauge plane .054 +.001 -.000 inch (1.37 +0.03 -0.00 mm) below seating plane shall be within .007 inch (0.18 mm) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC.
- 7. Dimension LU applies between L1 and L2. Dimension LD applies between L2 and LL minimum. Diameter is uncontrolled in L1 and beyond LL minimum.
- 8. All three leads.
- 9. The collector shall be internally connected to the case.
- 10. Dimension r (radius) applies to both inside corners of tab.
- 11. In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.
- 12. Lead 1 = emitter, lead 2 = base, lead 3 = collector.

FIGURE 1. Physical dimensions TO-18 (2N2369A).

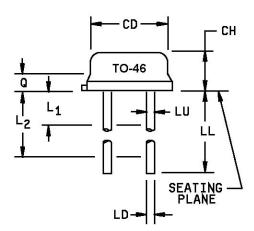
T4-LDS-0057 Rev. 3 (110213) Page 3 of 8

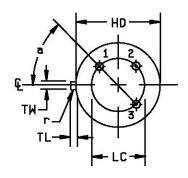


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TECHNICAL DATA SHEET

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	Dimensions				
Ltr	Inc	hes	Millimeters		Notes
	Min	Max	Min	Max	
CD	.178	.195	4.52	4.95	
СН	.065	.085	1.65	2.16	
HD	.209	.230	5.31	5.84	
LC	.100	.100 TP		1 TP	5
LD	.016	.021	0.41	0.53	
LL	.500	1.750	12.70	44.45	6
LU	.016	.019	0.41	0.48	6
L_1		.050		1.27	6
L_2	.250		6.35		6
Q		.040		1.02	3
TL	.028	.048	0.71	1.22	8
TW	.036	.046	0.91	1.17	4
r		.010		0.25	9
α	45°	TP	45° TP		

NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Symbol TL is measured from HD maximum.
- 4. Details of outline in this zone are optional.
- 5. Leads at gauge plane .054 inch (1.37 mm) +.001 inch (0.03 mm) -.000 inch (0.00 mm) below seating plane shall be within .007 inch (0.18 mm) radius of TP relative to tab. Device may be measured by direct methods or by gauge.
- 6. Symbol LU applies between L1 and L2. Dimension LD applies between L2 and LL minimum.
- 7. Lead number three is electrically connected to case.
- 8. Beyond r maximum, TW shall be held for a minimum length of .011 inch (0.28 mm).
- 9. Symbol r applied to both inside corners of tab.
- 10. In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.
- 11. Lead 1 is emitter, lead 2 is base, and lead 3 is collector.

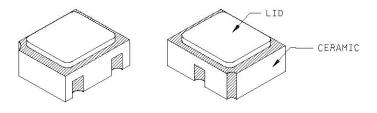
FIGURE 2. Physical dimensions - TO-46 (2N4449).

T4-LDS-0057 Rev. 3 (110213) Page 4 of 8



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NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Hatched areas on package denote metallized areas.
- 4. Lid material: Kovar.
- 5. Pad 1 = Base, Pad 2 = Emitter, Pad 3 = Collector, Pad 4 = Shielding connected to the lid.
- In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.

	Dimensions				
Ltr	Inches		Millimeter		Notes
	Min	Max	Min	Max	
BH	.046	.056	1.17	1.42	
BL	.115	.128	2.92	3.25	
BW	.085	.108	2.16	2.74	
CL		.128		3.25	
CW		.108		2.74	
LL1	.022	.038	0.56	0.96	
LL2	.017	.035	0.43	0.89	
LS1	.036	.040	0.91	1.02	
LS2	.071	.079	1.81	2.01	
LW	.016	.024	0.41	0.61	
r		.008		.203	
r1		.012		.305	
r2		.022		.559	

FIGURE 3. Physical dimensions - surface mount (UB version, 2N2369AUB).

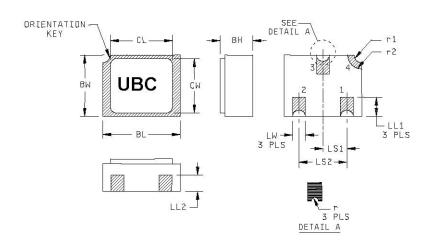
T4-LDS-0057 Rev. 3 (110213) Page 5 of 8

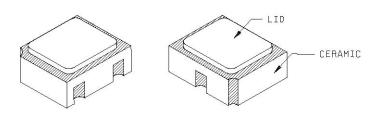


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Symbol	Dimensions				Note
Symbol	Inc	hes	Millir	neters	TVOIC
	Min	Max	Min	Max	
BH	.046	.071	1.17	1.80	
BL	.115	.128	2.92	3.25	
BW	.085	.108	2.16	2.74	
CL		.128		3.25	
CW		.108		2.74	
LL1	.022	.038	0.56	0.96	
LL2	.017	.035	0.43	0.89	

Symbol	Dimensions				Note	
Symbol	Inc	hes	Millin	neters	Note	
	Min	Max	Min	Max		
LS1	.036	.040	0.91	1.02		
LS2	.071	.079	1.81	2.01		
LW	.016	.024	0.41	0.61		
r		.008		.203		
r1		.012		.305		
r2		.022		.559		

NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Hatched areas on package denote metallized areas
- 4. Pad 1 = Base, Pad 2 = Emitter, Pad 3 = Collector, Pad 4 = connected to the lid braze ring.
- 5. In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.

FIGURE 4. Physical dimensions, surface mount (UBC version, ceramic lid).

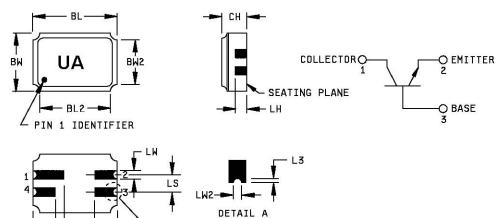
T4-LDS-0057 Rev. 3 (110213) Page 6 of 8



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	Dimensions					
Ltr.	Inc	hes	Millir	neters		
	Min	Max	Min	Max		
BL	.215	.225	5.46	5.71		
BL2		.225		5.71		
BW	.145	.155	3.68	3.93		
BW2		.155		3.93		
СН	.061	.075	1.55	1.90		
L3	.003	.007	0.08	0.18		
LH	.029	.042	0.74	1.07		
LL1	.032	.048	0.81	1.22		
LL2	.072	.088	1.83	2.23		
LS	.045	.055	1.14	1.39		
LW	.022	.028	0.56	0.71		
LW2	.006	.022	0.15	0.56		

Pin number.	1	2	3	4
Transistor	Collector	Emitter	Base	N/C

NOTES:

- Dimensions are in inches.
- 2. Millimeters are given for general information only.

DETAIL A

- Dimension CH controls the overall package thickness. When a window lid is used, dimension CH must increase by a minimum of .010 inch (0.254 mm) and a maximum of .040 inch (1.020 mm).
- The corner shape (square, notch, radius) may vary at the manufacturer's option, from that shown on the drawing.
- Dimensions LW2 minimum and L3 minimum and the appropriate castellation length define an unobstructed threedimensional space traversing all of the ceramic layers in which a castellation was designed. (Castellations are required on the bottom two layers, optional on the top ceramic layer.) Dimension LW2 maximum and L3 maximum define the maximum width and depth of the castellation at any point on its surface. Measurement of these dimensions may be made prior to solder dipping.
- The co-planarity deviation of all terminal contact points, as defined by the device seating plane, shall not exceed .006 inch (0.15mm) for solder dipped leadless chip carriers.
- In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.

FIGURE 5. Physical dimensions - surface mount (UA version).

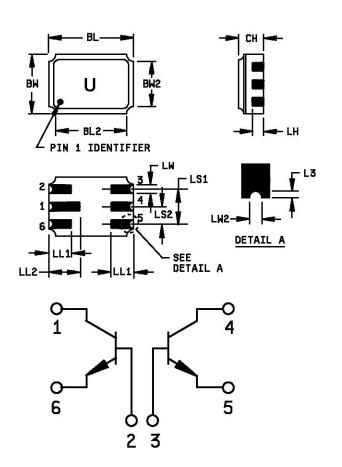
T4-LDS-0057 Rev. 3 (110213) Page 7 of 8



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	Dimensions					
Ltr.	Inches		Millimeters			
	Min	Max	Min	Max		
BL	.240	.250	6.10	6.35		
BL2		.250		6.35		
BW	.165	.175	4.19	4.44		
BW2		.175		4.44		
СН	.066	.080	1.68	2.03		
L3	.003	.007	0.08	0.18		
LH	.026	.039	0.66	0.99		
LL1	.060	.070	1.52	1.78		
LL2	.082	.098	2.08	2.49		
LS1	.095	.105	2.41	2.67		
LS2	.045	.055	1.14	1.39		
LW	.022	.028	0.56	0.71		
LW2	.006	.022	0.15	0.56		

Pin number	1	2	3	4	5	6
Transistor	Collector no. 1	Base no. 1	Base no. 2	Collector no. 2	Emitter no. 2	Emitter no. 1

NOTES:

- 1. 1.Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Dimension CH controls the overall package thickness. When a window lid is used, dimension CH must increase by a minimum of .010 inch (0.254 mm) and a maximum of .040 inch (1.020 mm).
- The corner shape (square, notch, radius) may vary at the manufacturer's option, from that shown on the drawing.
- Dimensions LW2 minimum and L3 minimum and the appropriate castellation length define an unobstructed threedimensional space traversing all of the ceramic layers in which a castellation was designed. (Castellations are required on the bottom two layers, optional on the top ceramic layer.) Dimension LW2 maximum and L3 maximum define the maximum width and depth of the castellation at any point on its surface. Measurement of these dimensions may be made prior to solder dipping.
- The co-planarity deviation of all terminal contact points, as defined by the device seating plane, shall not exceed .006 inch (0.15mm) for solder dipped leadless chip carriers.
- In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.

FIGURE 6. Physical dimensions - surface mount (dual transistors, U version only, 2N2369AU).

T4-LDS-0057 Rev. 3 (110213) Page 8 of 8